

# Luttinger-liquid behavior in single-walled carbon nanotube networks

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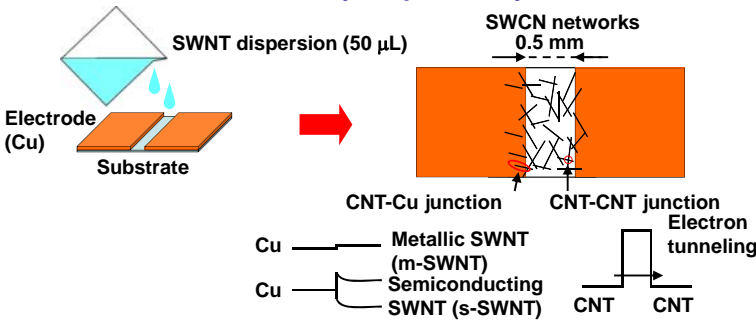
## Introduction

Elucidating the electrical transport properties of single-walled carbon nanotube (SWNT) networks

➔ Making full use of excellent SWNT properties

## Fabrication method

SWNTs were individually dispersed by sodium cholate



## Conductance measurement

Conductance before and after soaking

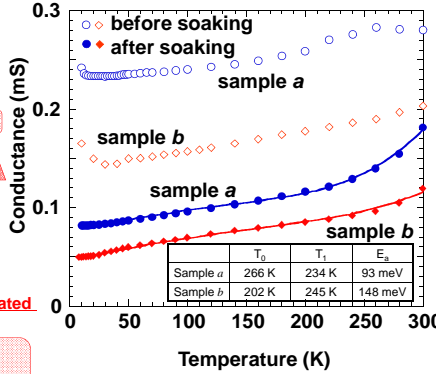
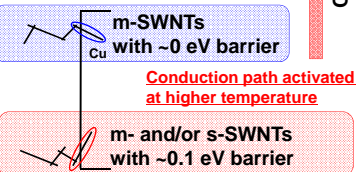
Soaked in water to remove sodium cholate

After soaking

$$G = g_1 \exp[-T_1/(T+T_0)] + g_2 \exp(-E_b/k_B T)$$

(Fluctuation induced tunneling (FIT) model)

Dominant conduction path at lower temperature

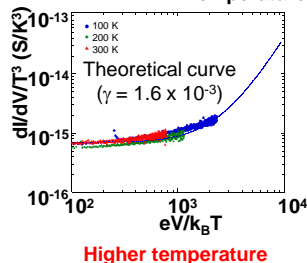
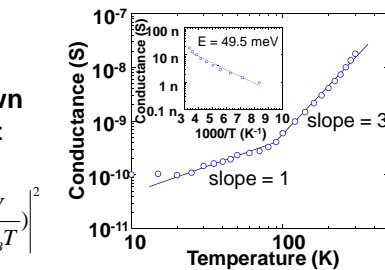
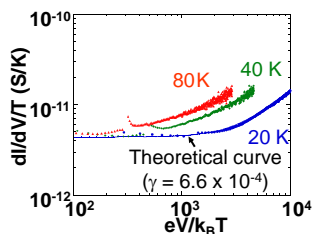


## Luttinger-liquid behavior

Sample a

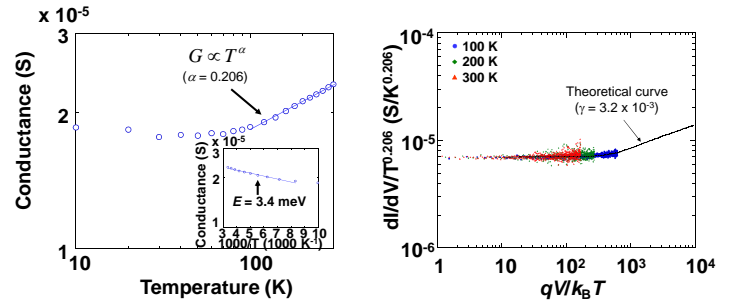
- Biased at 80 V for 20 h to remove metallic path
- m-SWNTs were broken down
- Luttinger-liquid behavior at higher temperature

$$\frac{dI}{dV} \propto T^\alpha \cosh\left(\gamma \frac{eV}{2k_B T}\right) \Gamma\left(\frac{1+\alpha}{2} + \gamma \frac{ieV}{2\pi k_B T}\right)^2$$

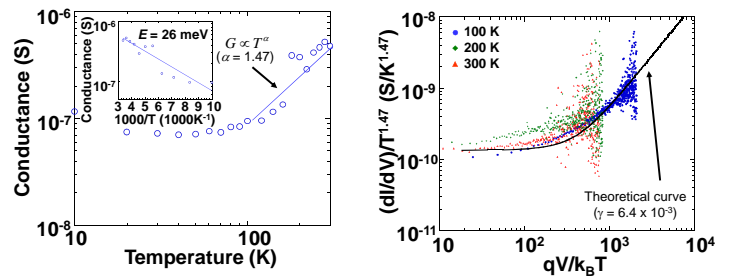


Sample b

After 1st break down (40 V for 26.5 h)

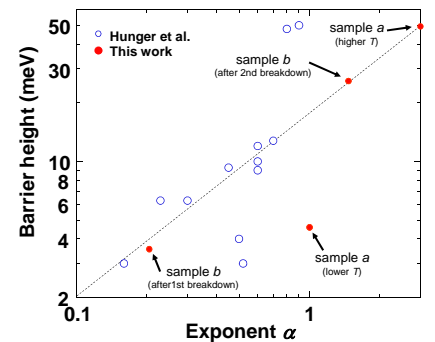


After 2nd break down (45 V for 2 h)



Increased exponent  $\alpha$  as the breakdown proceeded

Correlation between Barrier height and exponent  $\alpha$



\* Th. Hunger, B. Lengeler, and J. Appenzeller. *Phys. Rev. B* 69, 195406 (2004)

In good agreement with data reported by Hunger et al.

## Conclusion

- Pristine SWNT networks obeyed FIT and thermally activated conduction.
- Electrical breakdown caused Luttinger-liquid behavior.
- The relation between barrier height and exponent  $\alpha$  was in good agreement with that reported previously.

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